Declaration for Patent Application

Docket Number: 1875.4170000/JTH/GSB

As a below named inventor, I hereby declare that:

My residence, mailing address and citizenship are as stated below next to my name.

I believe I am an original, first and joint inventor of the subject matter that is claimed and for which a patent is sought on the invention entitled: <u>High Voltage Power Management Unit Architecture In CMOS Process</u>,

the specification of which is attached hereto unless the following box is checked:

1					
0	was filed on <u>herewith;</u> as United States Applie was amended on		Γ International Application Number <u>to be assignable</u> fapplicable).	g <u>ned;</u> and	
-	state that I have review d by any amendment ref		e contents of the above identified specification	, including the cl	laims, as
continu	ation-in-part applications	s, material information	material to patentability as defined in 37 C.F. n that became available between the filing date e continuation-in-part application.		
patent, at least o box, any	inventor's or plant breed one country other than the foreign application for	ler's rights certificate(he United States of Ar patent, inventor's or p	C. § 119(a)-(d) or (f), or § 365(b) of any forei (s), or § 365(a) of any PCT international appliemerica, listed below and have also identified bolant breeder's rights certificate(s), or PCT intervhich priority is claimed.	cation, which des elow, by checking	signated
Prior Fo	reign Application(s)			Priority (Claimed
(Applica	ation No.)	(Country)	(Day/Month/Year Filed)	□ Yes	□ No
(Applica	ation No.)	(Country)	(Day/Month/Year Filed)	□ Yes	□ No
Send Co	orrespondence to:	1100 N	SLER, GOLDSTEIN & FOX P.L.L.C. New York Avenue, N.W. ngton, D.C. 20005-3934		·
Direct T	elephone Calls to:		(202) 371-2600		

Appl. No.: *To Be Assigned* Docket No.: 1875.4170000/JTH/GSB

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under 18 U.S.C. § 1001 and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

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